NSN 5961-01-363-5741

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-363-5741 **Inclosure Material:** Plastic **Overall Length:** 8.26 millimeters **Overall Height:** 8.63 millimeters **Overall Width:** 5.03 millimeters **Internal Configuration:** Field effect **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -100.0 drain to source voltage and -40.0 gate to source voltage **Current Rating Per Characteristic:** 1.00 amperes drain current **Power Rating Per Characteristic:** 1.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 4 printed circuit Shelf Life: N/a **Unit Of Measure:** Demilitarization: No